



# PJD100P03

## 30V P-Channel Enhancement Mode MOSFET

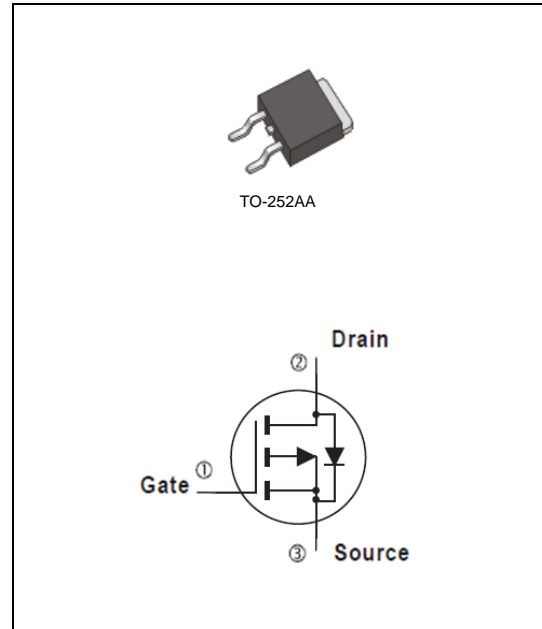
<b>Voltage</b>	<b>-30 V</b>	<b>Current</b>	<b>-100 A</b>
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### Features

- $R_{DS(ON)}$ ,  $V_{GS}@-10V, I_D@-20A < 4.5m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@-4.5V, I_D@-15A < 7m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case : TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Weight : 0.0104 ounces, 0.297grams



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		$V_{DS}$	-30	V
Gate-Source Voltage		$V_{GS}$	+20	V
Continuous Drain Current	$T_C=25^\circ C$	$I_D$	-100	A
	$T_C=100^\circ C$		-63	
Pulsed Drain Current (Note 1)	$T_C=25^\circ C$	$I_{DM}$	-400	
Power Dissipation	$T_C=25^\circ C$	$P_D$	104	W
	$T_C=100^\circ C$		42	
Continuous Drain Current	$T_A=25^\circ C$	$I_D$	-15.8	A
	$T_A=70^\circ C$		-12.6	
Power Dissipation	$T_A=25^\circ C$	$P_D$	2.0	W
Power Dissipation	$T_A=70^\circ C$		1.3	
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	$^\circ C$
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{\theta JC}$	1.2	$^\circ C/W$
	Junction to Ambient	$R_{\theta JA}$	62.5	

- Limited only By Maximum Junction Temperature



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## Electrical Characteristics (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-30	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-1	-1.6	-2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-20A	-	3.9	4.5	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-15A	-	5.7	7	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V	-	-	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	-	-	±100	nA
<b>Dynamic</b> (Note 6)						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =-15V, I <sub>D</sub> =-10A, V <sub>GS</sub> =-10V (Note 2,3)	-	107	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	18	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	18	-	
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =-25V, V <sub>GS</sub> =0V, f=1.0MHZ	-	6067	-	pF
Output Capacitance	C <sub>oss</sub>		-	709	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	361	-	
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>DS</sub> =-15V, I <sub>D</sub> =-1A, V <sub>GS</sub> =-10V, R <sub>G</sub> =6Ω (Note 2,3)	-	22	-	ns
Turn-On Rise Time	t <sub>r</sub>		-	48	-	
Turn-Off Delay Time	t <sub>d(off)</sub>		-	197	-	
Turn-Off Fall Time	t <sub>f</sub>		-	90	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>	---	-	-	-100	A
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-1A, V <sub>GS</sub> =0V	-	-0.68	-1	V

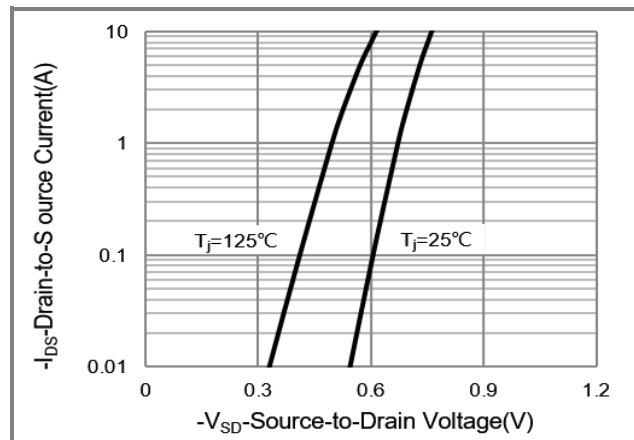
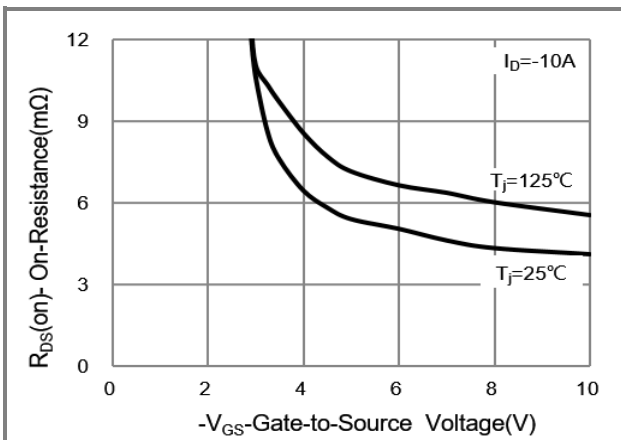
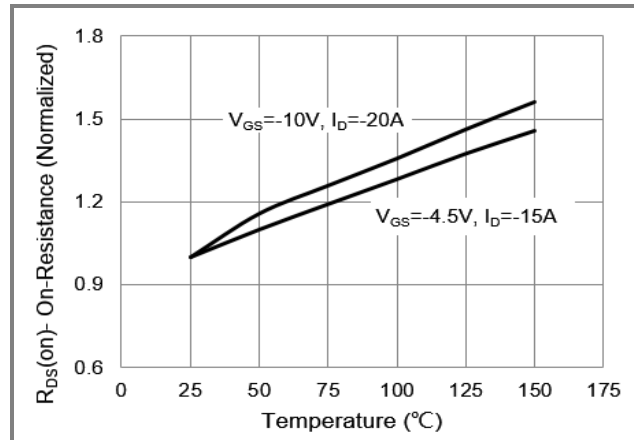
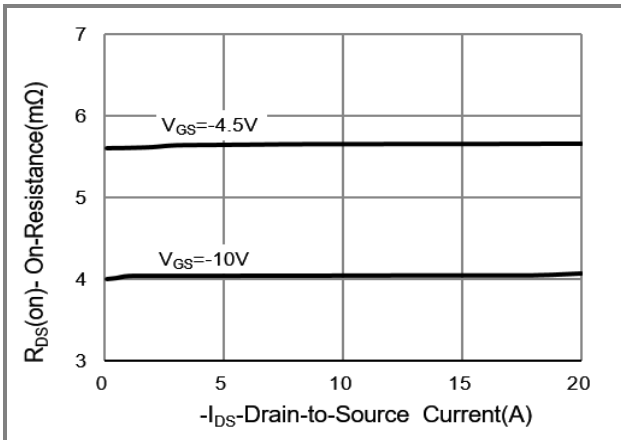
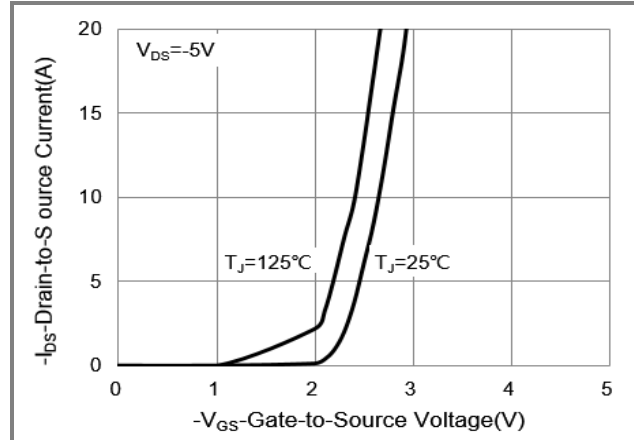
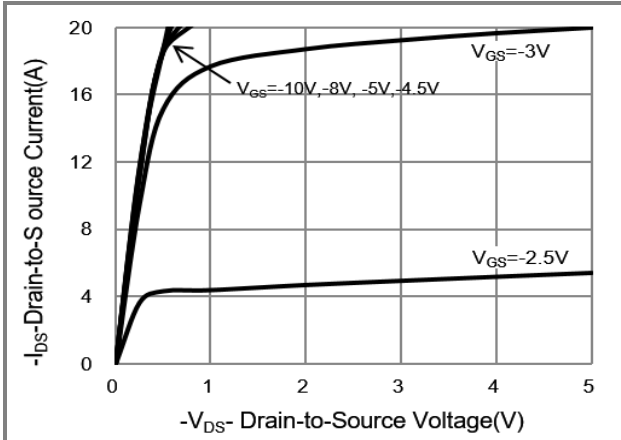
**NOTES :**

1. Pulse width ≤ 300us, Duty cycle ≤ 2%
2. Essentially independent of operating temperature typical characteristics
3. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> = 25°C.
4. The maximum current rating is package limited
5. R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
6. Guaranteed by design, not subject to production testing



# PJD100P03

## TYPICAL CHARACTERISTIC CURVES





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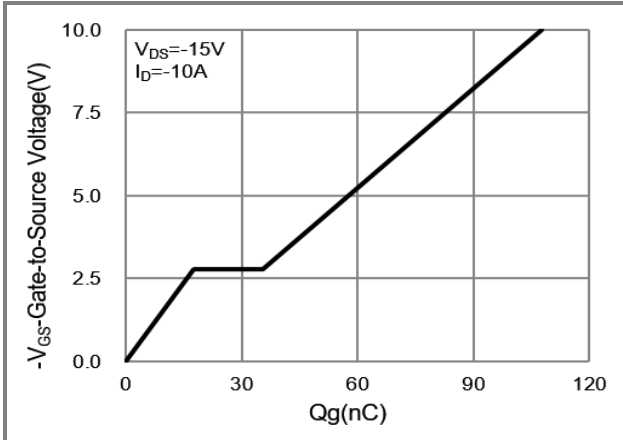


Fig.7 Gate Charge

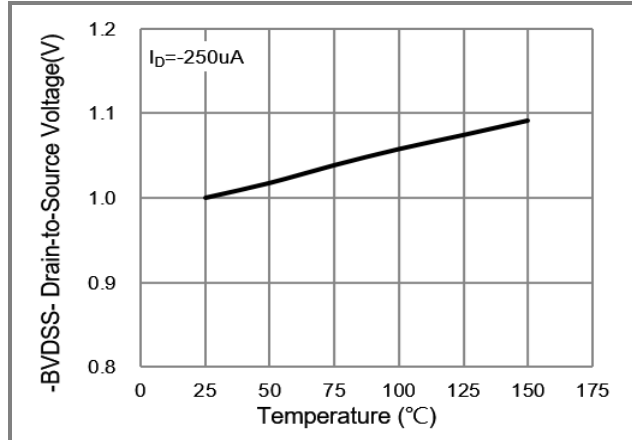


Fig.8 Breakdown Voltage Variation vs. Temperature

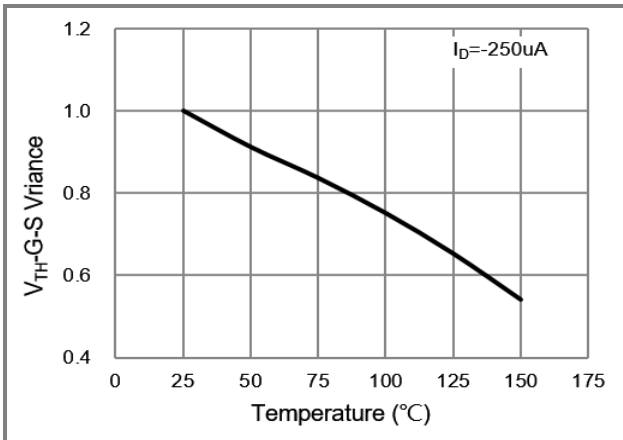


Fig.9 Threshold Voltage Variation with Temperature

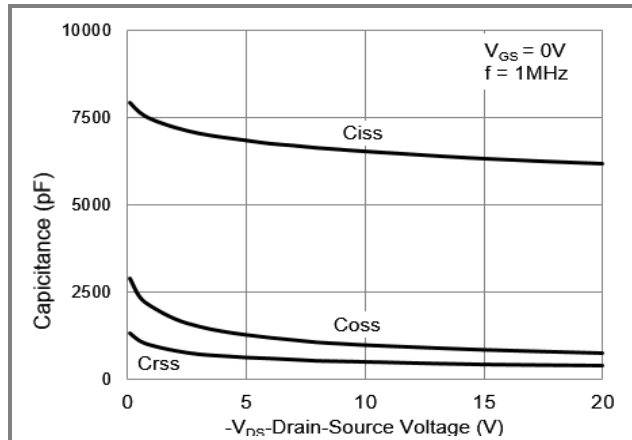


Fig.10 Capacitance vs. Drain-Source Voltage

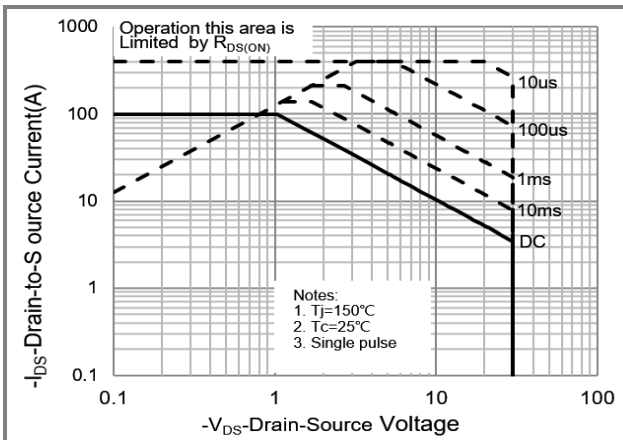


Fig.11 Maximum Safe Operating Area



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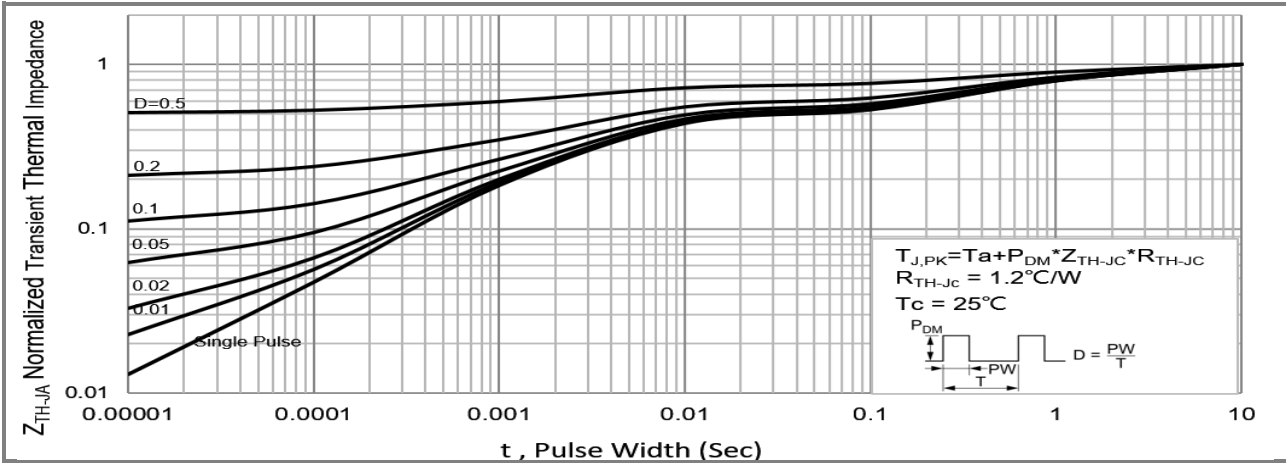
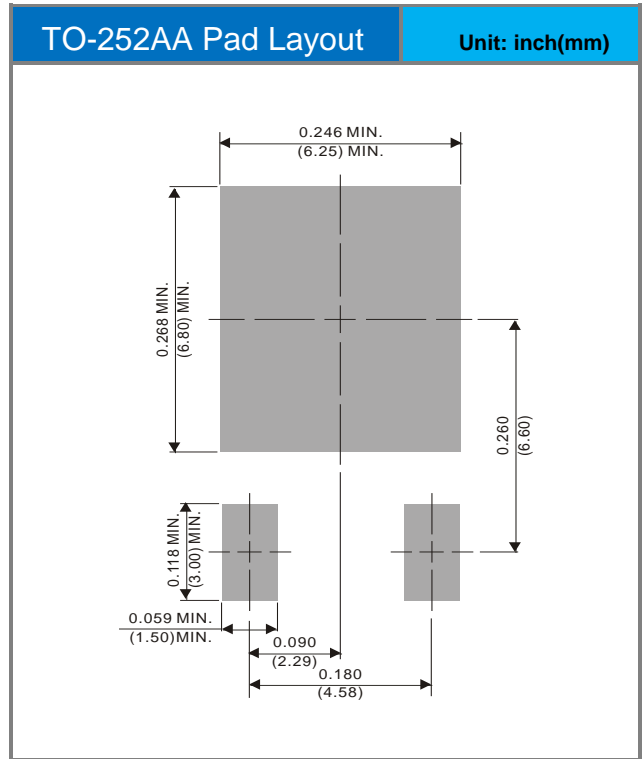
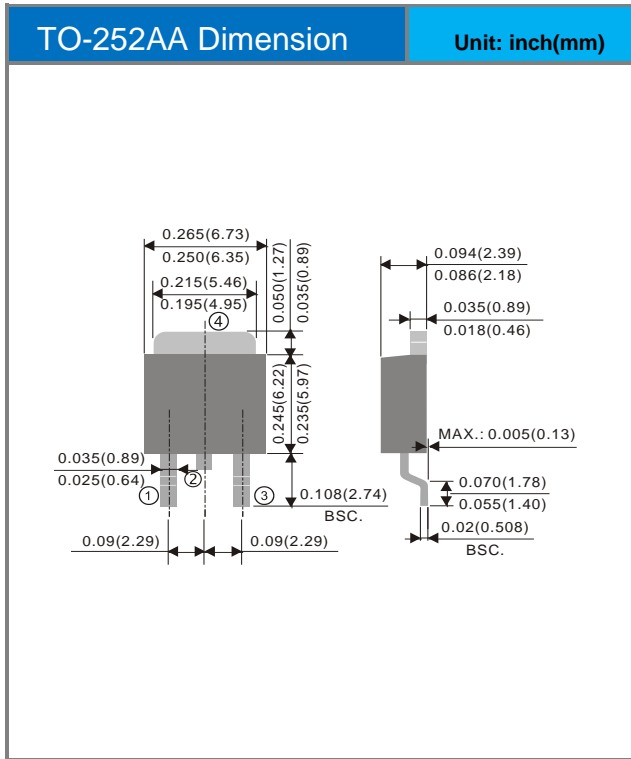


Fig.13 PJP100P03 Normalized Transient Thermal Impedance vs. Pulse Width



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## Packaging Information





# PJD100P03

## PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJD100P03_L2_00001	TO-252AA	3,000pcs / 13" reel	D100P03	Halogen free



## PJD100P03

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